

General Description

The MAX4784 is a low on-resistance, low-voltage, quad 2:1 analog multiplexer that operates from a single +1.6V to +3.6V supply. This device has fast switching speeds (ton = 25ns, toff = 10ns max), handles Rail-to-Rail® analog signals, and consumes less than 1µW of quiescent power.

When powered from a +3V supply, the MAX4784 features low 1Ω (max) on-resistance (RON), with 0.15Ω (max) R_{ON} matching and 0.2Ω (max) R_{ON} flatness. The digital logic input is +1.8V CMOS-logic compatible when using a single +3V supply.

The MAX4784 is available in 16-pin TSSOP and 4mm × 4mm QFN packages.

Applications

Power Routing

Battery-Powered Systems

Audio and Video Signal Routing

Low-Voltage Data-Acquisition Systems

Communications Circuits

PCMCIA Cards

Cellular Phones

Modems

Hard Drives

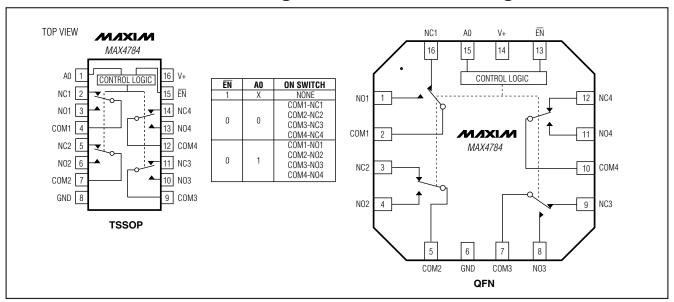
Features

- ♦ Low Ron:
 - 1Ω max (+3V Supply) 3Ω max (+1.8V Supply)
- ♦ 0.2Ω max Ron Flatness (+3V Supply)
- ♦ +1.6V to +3.6V Single-Supply Operation
- **♦ Available in TSSOP and QFN Packages**
- ♦ High-Current Handling Capacity (150mA Continuous)
- ♦ +1.8V CMOS Logic Compatible (+3V Supply)
- ♦ Fast Switching: toN = 25ns, toFF = 10ns

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
MAX4784EGE	-40°C to +85°C	16 QFN
MAX4784EUE	-40°C to +85°C	16 TSSOP

Pin Configurations/Functional Diagrams/Truth Table



Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

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Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to GND	
V+, A0, EN	0.3V to +4V
COM_, NO_, NC_ (Note 1)	0.3V to $(V+ + 0.3V)$
Continuous Current COM_, NO_, NC	±150mA
Peak Current COM_, NO_, NC_	
(pulsed at 1ms 10% duty cycle)	±300mA

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
16-Pin QFN (derate 18.5mW/°C above +70°C)1	
16-Pin TSSOP (derate 9.4mW/°C above +70°C)	.755mW
Operating Temperature Range40°C to	o +85°C
Maximum Junction Temperature	.+150°C
Storage Temperature Range65°C to	+150°C

Note 1: Signals on COM_, NO_, or NC_ exceeding V+ or GND are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single +3V Supply

 $(V+=+2.7V \text{ to } +3.6V, V_{IH}=+1.4V, V_{IL}=+0.5V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified. Typical values are at } V+=+3.0V, T_A=+25^{\circ}C.)$ (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS	
ANALOG SWITCH								
Analog Signal Range	V _{COM} _, V _{NO} _, V _{NC} _			0		V+	V	
On-Resistance (Note 4)	Ron	V+ = 2.7V, ICOM = 100mA,	+25°C		0.7	1	Ω	
On-nesistance (Note 4)	HOM	V_{NO} or V_{NC} = 1.5V	T _{MIN} to T _{MAX}			1.2	52	
On-Resistance Match Between Channels	ΔRON	V+ = 2.7V, I _{COM} _ = 100mA,	+25°C		0.1	0.15	Ω	
(Notes 4, 5)	ΔhON	V_{NO} or V_{NC} = 1.5V	T _{MIN} to T _{MAX}			0.2	22	
On-Resistance Flatness	D	V+ = 2.7V,	+25°C		0.1	0.2	0	
(Note 6)	R _{FLAT} (ON)	I _{COM} = 100mA, V _{NO} or V _{NC} = 1V, 1.5V, 2V	T _{MIN} to T _{MAX}			0.3	Ω	
NO_ or NC_ Off-Leakage	INO_(OFF),	V+ = 3.6V,	+25°C	-1	±0.002	+1	·- Λ	
Current (Note 7)	INC_(OFF)	V _{COM} = 0.3V, 3.3V, V _{NO} or V _{NC} = 3.3V, 0.3V	T _{MIN} to T _{MAX}	-5		+5	nA	
COM_ Off-Leakage Current	1	V+ = 3.6V, V _{COM} _ = 0.3V, 3.3V,	+25°C	-1	±0.002	+1	A	
(Note 7)	ICOM_(OFF)	V_{NO} or V_{NC} = 3.3V, 0.3V, or floating	T _{MIN} to T _{MAX}	-5		+5	nA	
COM_ On-Leakage Current	1	V+ = 3.6V, V _{COM} _ = 3.3V, 0.3V,	+25°C	-2	±0.002	+2	^	
(Note 7)	ICOM_(ON)	V_{NO} or V_{NC} = 3.3V, 0.3V, or floating	T _{MIN} to T _{MAX}	-10		+10	nA	

2 ______*NIXIM*

ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

 $(V+=+2.7V \text{ to } +3.6V, V_{IH}=+1.4V, V_{IL}=+0.5V, T_A=T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified. Typical values are at } V+=+3.0V, T_A=+25^{\circ}C.)$ (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
SWITCH DYNAMIC CHARAC	TERISTICS						
Turn-On Time	ton	$V_{NO_{-}}, V_{NC_{-}} = 1.5V,$ $R_{L} = 50\Omega, C_{L} = 35pF,$	+25°C		20	25	ns
Turn on Time	ION	Figure 1	T _{MIN} to T _{MAX}			30	110
Turn-Off Time	torr	$V_{NO_{-}}, V_{NC_{-}} = 1.5V,$ $R_{L} = 50\Omega, C_{L} = 35pF,$	+25°C		8	10	ns
rum-on time	toff	Figure 1	T _{MIN} to T _{MAX}			18	115
Break-Before-Make (Note 8)	t _{BBM}	V_{NO} , V_{NC} = 1.5V, R_L = 50 Ω , C_L = 35pF,	+25°C		7		ns
Broak Boloro Mako (Note o)	rbbivi	Figure 2	T _{MIN} to T _{MAX}	1			110
Charge Injection	Q	$V_{GEN} = 0$, $R_{GEN} = 0$, $C_L = 1.0$ nF, Figure 3	+25°C		5		рС
NO_ or NC_ Off-Capacitance	Coff	f = 1MHz, Figure 4	+25°C		33		рF
COM_ Off-Capacitance	CCOM_(OFF)	f = 1MHz, Figure 4	+25°C		60		рF
COM_ On-Capacitance	C _{COM} (ON)	f = 1MHz, Figure 4	+25°C		85		рF
-3dB On-Channel Bandwidth	BW	Signal = 0, $R_{IN} = R_{OUT} = 50\Omega$, $C_L = 5pF$, Figure 5			123		MHz
Off-Isolation (Note 9)	V _{ISO}	$f = 1MHz$, $V_{COM} = 1V_{P-P}$, $R_L = 50\Omega$, $C_L = 5pF$, Figure 5	+25°C		-67		dB
Crosstalk (Note 10)	VcT	$f = 1MHz$, $V_{COM} = 1V_{P-P}$, $R_L = 50\Omega$, $C_L = 5pF$, Figures 4, 5	+25°C		-95		dB
Total Harmonic Distortion	THD	f = 20Hz to 20kHz, V_{COM} = 2 V_{P-P} , R_L = 32 Ω	+25°C		0.008		%
LOGIC INPUT (A0, EN)							
Input Logic High	VIH			1.4			V
Input Logic Low	V _{IL}					0.5	V
Input Leakage Current I _{IN}		$V_{\overline{EN}} = 0 \text{ or } +3.6V,$ $V_{A0} = 0 \text{ or } +3.6V$		-1	0.005	+1	μΑ
POWER SUPPLY							
Power-Supply Range	V+			1.6		3.6	V
Positive Supply Current	l+	$V+=3.6V$, \overline{EN} , $A0=0$ or $V+$, all channels on or off	T _{MIN} to T _{MAX}	_		2	μA

ELECTRICAL CHARACTERISTICS—Single +1.8V Supply

 $(V+=+1.8V,\ V_{IH}=+1.0V,\ V_{IL}=+0.4V,\ T_A=T_{MIN}\ to\ T_{MAX},\ unless\ otherwise\ specified.$ Typical values are at $T_A=+25^{\circ}C.)$ (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS	
ANALOG SWITCH	•		•				•	
Analog Signal Range	V _{COM} _, V _{NO} _, V _{NC} _			0		V+	V	
On-Resistance	Ron	I _{COM} _ = 10mA,	+25°C		2	3	Ω	
	11014	V_{NO} or V_{NC} = 1.0V	T _{MIN} to T _{MAX}			5		
NO_ or NC_ Off-Leakage	I _{NO_(OFF)} ,	$V_{COM} = 0.3V, 1.5V, V_{NO} \text{ or } V_{NC} = 1.5V,$	+25°C	-1		+1	nA	
Current (Note 7)	INC_(OFF)	0.3V	T _{MIN} to T _{MAX}	-5		+5		
COM_ Off-Leakage Current	ICOM (OFF)	$V_{COM} = 0.3V, 1.5V,$ V_{NO} or $V_{NC} = 1.5V,$	+25°C	-1		+1	- nA	
(Note 7)	ICOM_(OFF)	0.3V	T _{MIN} to T _{MAX}	-5		+5		
COM_ On-Leakage Current	ICOM_(ON)	V _{COM} = 0.3V, 1.5V, V _{NO} or V _{NC} = 0.3V,	+25°C	-2		+2	nA	
(Note 7)	ICOM_(ON)	1.5V, or floating	T _{MIN} to T _{MAX}	-10 +		+10	117 (
SWITCH DYNAMIC CHARACT	ERISTICS							
Turn-On Time	ton	$V_{NO}, V_{NC} = 1.0V,$ $R_1 = 50\Omega, C_1 = 35pF,$	+25°C		25	30	ns	
Turri Ori Time	UN	Figure 1	T _{MIN} to T _{MAX}			35	113	
Turn-Off Time	toff	$V_{NO_{-}}, V_{NC_{-}} = 1.0V,$ $R_{L} = 50\Omega, C_{L} = 35pF,$	+25°C		10	15	ns	
Turr-On Time	IOFF	Figure 1	T _{MIN} to T _{MAX}			20	115	
Drock Defere Make (Note 9)	t	V _{NO} _, V _{NC} _ = 1.0V,	+25°C		10		— ns	
Break-Before-Make (Note 8)	tBBM	$R_L = 50\Omega$, $C_L = 35pF$, Figure 2	T _{MIN} to T _{MAX}	1				
Charge Injection	Q	V _{GEN} = 0, R _{GEN} = 0, C _L = 1nF, Figure 3	+25°C		5		рС	

4 ______ MAXI/N

ELECTRICAL CHARACTERISTICS—Single +1.8V Supply (continued)

 $(V+=+1.8V, V_{IH}=+1.0V, V_{IL}=+0.4V, T_A=T_{MIN}$ to T_{MAX} , unless otherwise specified. Typical values are at $T_A=+25^{\circ}C.$) (Notes 2, 3)

PARAMETER SYI		CONDITIONS	TA	MIN	TYP	MAX	UNITS
LOGIC INPUT (A0, EN)							
Input Logic High	VIH			1			V
Input Logic Low	VIL					0.4	V
Input Leakage Current	I _{IN}	$V_{\overline{EN}} = 0 \text{ or } +3.6V, V_{A0} = 0 \text{ or } +3.6V$		-1		+1	μΑ

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.

Note 3: -40°C specifications are guaranteed by design.

Note 4: R_{ON} and ΔR_{ON} matching specifications for QFN packaged parts are guaranteed by design.

Note 5: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$.

Note 6: Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog signal ranges.

Note 7: Leakage parameters are 100% tested at T_A = +85°C, and guaranteed by correlation over the full rated temperature range.

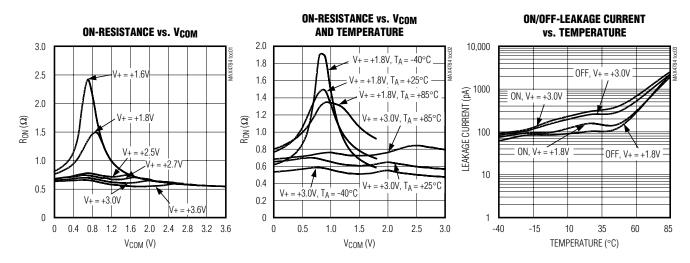
Note 8: Guaranteed by design.

Note 9: Off-Isolation = $20log_{10}(V_{COM}/V_{NO})$, V_{COM} = output, V_{NO} = input to off switch.

Note 10: Between two switches.

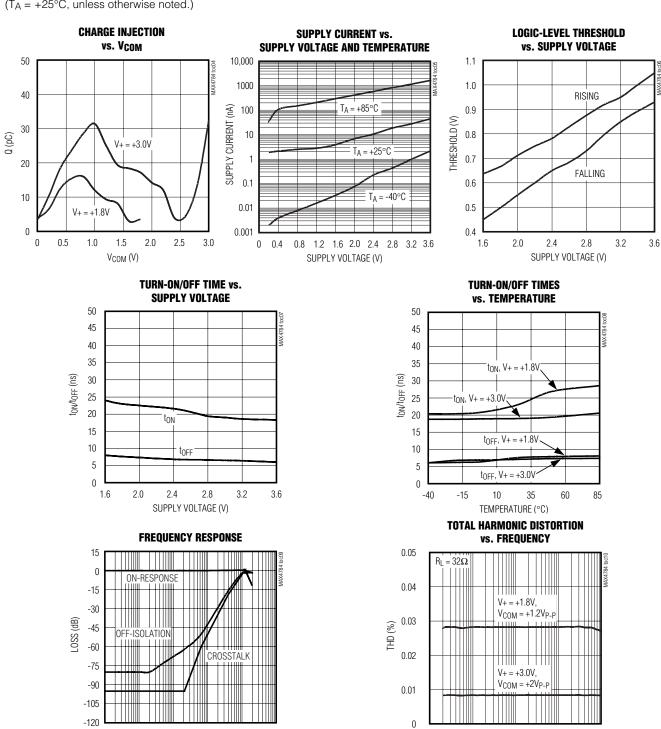
_Typical Operating Characteristics

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$



Typical Operating Characteristics (continued)

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$



1000

FREQUENCY (MHz)

10

1k

FREQUENCY (Hz)

MIXIM

0.01

Pin Description

PI	N		FUNCTION					
TSSOP	QFN	NAME	FUNCTION					
1	15	A0	Address Input					
2	16	NC1	Normally Closed Terminal					
3	1	NO1	Normally Open Terminal					
4	2	COM1	Analog Switch Common Terminal					
5	3	NC2	Normally Closed Terminal					
6	4	NO2	Normally Open Terminal					
7	5	COM2	Analog Switch Common Terminal					
8	6	GND	Ground					
9	7	СОМЗ	Analog Switch Common Terminal					
10	8	NO3	Normally Open Terminal					
11	9	NC3	Normally Closed Terminal					
12	10	COM4	Analog Switch Common Terminal					
13	11	NO4	Normally Open Terminal					
14	12	NC4	Normally Closed Terminal					
15	13	ĒN	Enable. Connect to GND for normal operation. Connect to logic-level high to turn all switches off.					
16	14	V+	Positive Supply Voltage					

Detailed Description

The MAX4784 is a low 1Ω max (at V+ = +3V) on-resistance, low-voltage, quad 2:1 analog multiplexer/demultiplexer that operates from a +1.6V to +3.6V single supply. CMOS switch construction allows switching analog signals that are within the supply voltage range (GND to V+).

When powered from a +3V supply, the 1 Ω max RoN allows high continuous currents to be switched in a variety of applications.

Applications Information

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, followed by NO_, NC_, or COM_.

Although it is not required, power-supply bypassing improves noise margin and prevents switching noise propagation from the V+ supply to other components. A $0.1\mu F$ capacitor, connected from V+ to GND, is adequate for most applications.

Logic Inputs

The MAX4784 logic inputs can be driven up to +3.6V regardless of the supply voltage. For example, with a +1.8V supply, A0 and $\overline{\text{EN}}$ may be driven low to GND and high to +3.6V. Driving A0 and $\overline{\text{EN}}$ rail-to-rail minimizes power consumption. Drive $\overline{\text{EN}}$ low to enable the COM_ outputs. When $\overline{\text{EN}}$ is high, the COM_ outputs are high impedance.

Analog Signal Levels

Analog signals that range over the entire supply voltage (V+ to GND) can be passed with very little change in onresistance (see *Typical Operating Characteristics*). The switches are bidirectional, so the NO_, NC_, and COM_ pins can be used as either inputs or outputs.

Layout

High-speed switches require proper layout and design procedures for optimum performance. Reduce stray inductance and capacitance by keeping traces short and wide. Ensure that bypass capacitors are as close to the device as possible. Use large ground planes where possible.

Test Circuits/Timing Diagrams

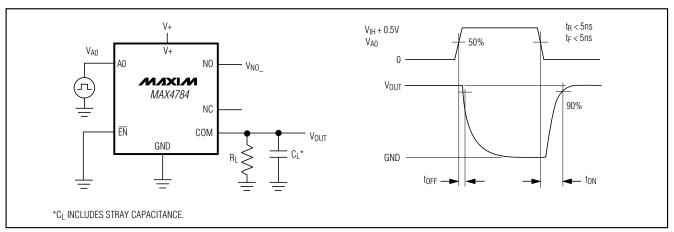


Figure 1. Turn-On and Turn-Off Times

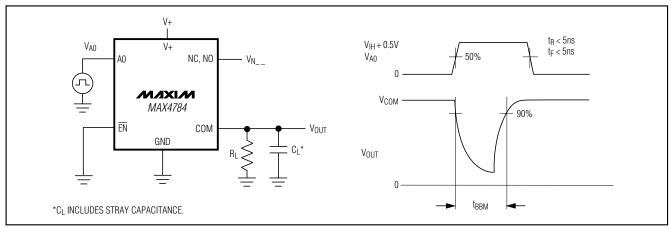


Figure 2. Break-Before-Make Interval

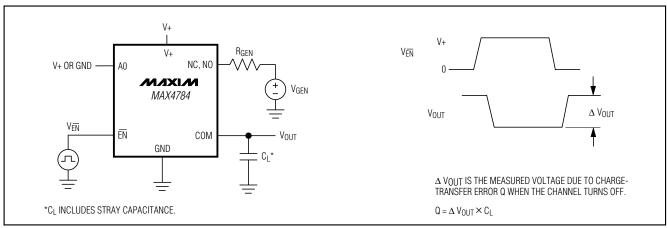


Figure 3. Charge Injection

Test Circuits/Timing Diagrams (continued)

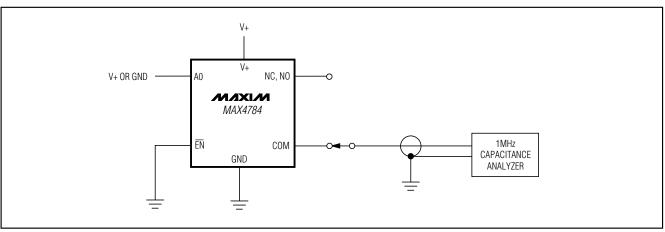


Figure 4. Capacitance

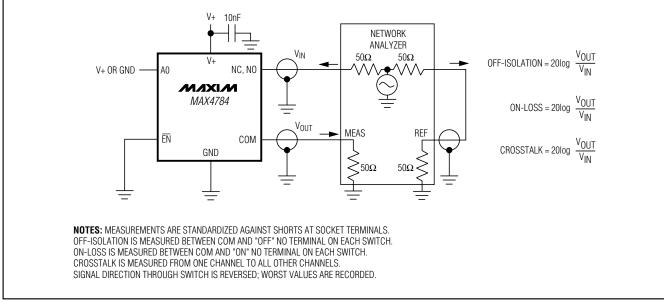


Figure 5. Off-Isolation, On-Loss, and Crosstalk

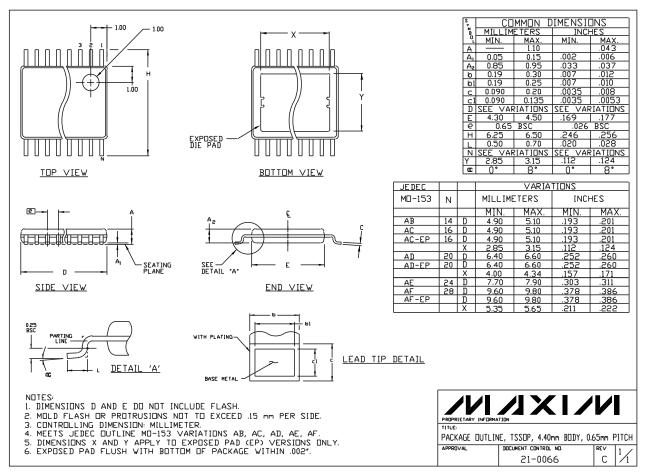
Chip Information

TRANSISTOR COUNT: 543

PROCESS: CMOS

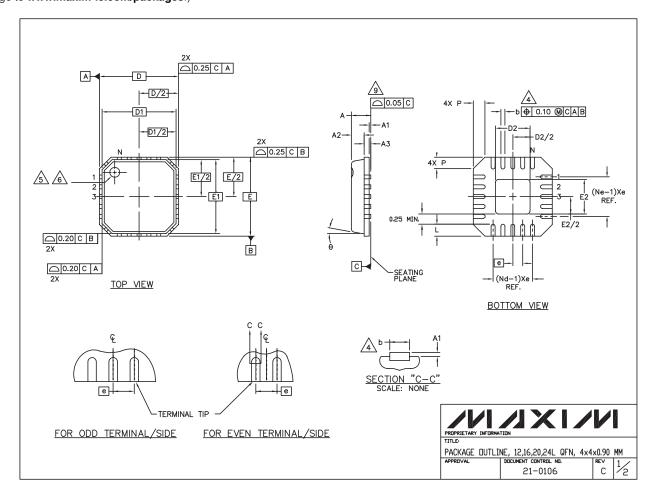
Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



Package Information (continued)

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Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)

NOTES:

- 1. DIE THICKNESS ALLOWABLE IS 0.305mm MAXIMUM (.012 INCHES MAXIMUM)
- 2. DIMENSIONING & TOLERANCES CONFORM MUST TO ASME Y14.5M. 1994.

Nd IS THE NUMBER OF TERMINALS.

Nd IS THE NUMBER OF TERMINALS IN X-DIRECTION & Ne IS THE NUMBER OF TERMINALS IN Y-DIRECTION.

DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.20 AND 0.25mm FROM TERMINAL TIP.

THE PIN #1 IDENTIFIER MUST BE EXISTED ON THE TOP SURFACE OF THE PACKAGE BY USING INDENTATION MARK OR INK/LASER MARKED.

6. EXACT SHAPE AND SIZE OF THIS FEATURE IS OPTIONAL.

7. ALL DIMENSIONS ARE IN MILLIMETERS.

8. PACKAGE WARPAGE MAX 0.05mm.

9. APPLIED FOR EXPOSED PAD AND TERMINALS.
EXCLUDE EMBEDDING PART OF EXPOSED PAD FROM MEASURING.

10. MEETS JEDEC MO220.

11. THIS PACKAGE OUTLINE APPLIES TO ANVIL SINGULATION (STEPPED SIDES) AND TO SAW SINGULATION (STRAIGHT SIDES) QFN STYLES.

S	COMMON								
S MBOL	DI	MENSION	1S	No.					
٥.	MIN.	NOM.	MAX.	Ϋ́E					
Α	0.80	0.90	1.00						
A1	0.00	0.01	0.05						
A2	0.00	0.65	0.80						
A A1 A2 A3 D D1 E E1 Θ		0.20 REF.							
D		4.00 BSC							
D1		3.75 BSC							
Ε		4.00 BSC							
E1		3.75 BSC							
θ	0.		12°						
	0.00	0.42	0.60						
D2 E2	0.75		2.25						
F2	0.75		2.25						

S Y M B	PITCH	VARIAT		N _O	S Y M B	PITCH	VARIAT		N _O	S Y M B	PITCH	VARIAT		N _O	S Y M B	PITCH	VARIATI	ON D	N _O
િ	MIN.	NOM.	MAX.	T _E	ို	MIN.	NOM.	MAX.	T _E	입	MIN.	NOM.	MAX.	TΕ	ଧ	MIN.	NOM.	MAX.	T _E
e		0.80 BSC			e		0.65 BSC			e		0.50 BSC			e		0.50 BSC		
N		12		3	N		16		3	N		20		3	N		24		3
Nd		3		3	Nd		4		3	Nd		5		3	Nd		6		3
Ne		3		3	Ne		4		3	Ne		5		3	Ne		6		3
	0.50	0.60	0.75		L	0.50	0.60	0.75		L	0.50	0.60	0.75		П	0.30	0.40	0.55	
Ь	0.28	0.33	0.40	4	b	0.23	0.28	0.35	4	Ь	0.18	0.23	0.30	4	Ь	0.18	0.23	0.30	4



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